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Flux pinning properties of YBCO films with nano-particles by TFA-MOD method

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Abstract

Nano-particles were doped into YBCO films as pinning centers by a metal organic deposition (MOD) method using trifluoroacetates. Two types of initial solution with a cation ratio of Y: Ba: Cu = 1: 1.5: 3 were prepared; one with the dispersion of $SnO₂$ particles with the size of 15-25 nm and the other one with the dispersion of smaller $ZrO₂$ particles with the size of under 8 nm, then the solution was spin-coated on $CeO₂/Gd₂Zr₂O₇/Hastelly$ substrates. The coated films were calcined at 430 °C in oxygen atmosphere and crystallized at 780 ºC in low oxygen atmosphere. From the results of X-ray diffraction analysis (XRD), peaks of $BaSnO₃$ were observed clearly in the YBCO film by the starting solution with $SnO₂$. On the other hands, little peaks corresponding to BaZrO₃ were observed in the film by the solution with ZrO₂. Many CuO segregations were recognized at the surface of $SnO₂$ doped YBCO film in comparison to the YBCO film with $ZrO₂$ doping. From these results, it is indicated that most of SnO₂ particles in precursors are react with Ba during heating. Critical current density (J_C) of the YBCO films by both solutions showed higher performance than that of pure YBCO film in magnetic fields.

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1. Introduction

 $REBa_2Cu_3O_{7-d}$ (REBCO, RE: rare earth elements) films have high critical current density (J_C) , high transition temperature (T_C) , and high irreversibility field (H_{ir}) so that these films are expected for applying superconducting wire. Metal organic deposition using trifluoroacetates (TFA-MOD) method is a promising procedure for YBCO films since this method can provide high superconducting properties in a cost-effective process with non-vacuum system [1–4]. However, J_c of YBCO films decreases in magnetic fields (**B**). So, in order to improve J_c in magnetic fields, various methods have been proposed for the introduction of effective artificial pinning centers (APCs) in superconducting films. It has been actually reported that J_C -**B** properties improved for REBCO films with BaZrO₃ particles of about 30 nm in diameter by the TFA-MOD method using a starting solution with dissolved Zr-salts [5-6]. Also, in our previous report, $SnO₂$ compounds were formed in the YBCO film with the size of about 30 nm by this method using a solution with dispersed $SnO₂$ particles and acted as pinning centers [7-8]. However, it is important to obtain higher J_C in

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magnetic fields for the electric power application, so higher number density of particles with smaller size is considered to be effective pinning centers in this method. In this study, we fabricated YBCO films by a starting solution with ZrO₂ particles which have the size of about under 8 nm and investigated the growth process of YBCO film with nanoparticles.

2. Experimental

YBCO films were fabricated by the TFA-MOD process. Starting solutions were prepared by dissolving Y-, Cuoctyl salts, and Ba-trifluoroacetates in an adequate solvent with a total metal ion concentration of 1.3 mol/L. We prepared two kinds of initial solutions which nano-particles were dispersed as pinning centers in; one with the dispersion of SnO₂ particles with the size of 15-25 nm, the other one with the dispersion ZrO₂ (Yttria-stabilized zirconia) with the size of under 8 nm. These particles were dispersed into the solution with the ratio of 2 mol%. The molar ratio of total metals in the solution is Y: Ba: Cu: M (M: Sn, Zr) = 1: 1.5: 3: 0.11. These solutions were deposited on $CeO₂/Gd₂Zr₂O₇/Hastellov$ substrates by a spin coating method at 3000 rpm for 120s. Then, two-step heat treatment was applied to the coated films. In the calcination step, these films were calcined up to 430°C at a heating rate of 5°C /min in oxygen atmosphere with water vapor of 2 vol.%. In order to fabricate thick precursor films, a process of coating and calcination were repeated for 3 times. Then, the calcined films were crystallized at a heating rate of 5°C /min and kept the maximum heating temperature of 780°C for 100 min in humid of 10 vol.% and low oxygen of 1000 ppm. Thickness of YBCO films were about 500-700 nm. Crystallinity of the films was characterized by XRD θ /2 θ scan. The surface morphology of films was observed by scanning electron microscopy (SEM) and SEM-EDX (Energy Dispersive X-ray Spectroscopy) to analyze the microstructure and composition of the films. The superconducting properties of YBCO films were measured by a DC four probe method.

3. Results and discussion

3.1. Crystallized phases in YBCO films

with 2 mol% $SnO₂$ and $ZrO₂$ addition.

The result of XRD θ /2 θ scan for YBCO films with 2 mol% nano-particles are shown in Fig 1. The vertical axis in the figure shows peak intensities which divided by the peak intensity of $CeO₂$ (200). The result of pure YBCO film was described as a reference in the figure. The peaks of $SnO₂(110)$, $BaSnO₃(110)$ and $BaSnO₃(200)$ were detected at 26.5°, 30°, and 42.5°, respectively, in SnO₂ added YBCO film. In the film with ZrO₂ addition, the peaks of ZrO₂ (111) and BaZrO₃ (200) were detected at 30° and 43°, respectively. In addition, the peak of $Y_2Cu_2O_5$ (211) and CuO (111) were detected in both films with nano-particles addition at 31° and 35°, respectively.

In order to investigate differences of products in each film, higher concentration of particles were introduced to the starting solution and then YBCO films were fabricated. The result of comparison between 2 mol% particles doped film and 8 mol% doped one is shown in Fig 2. In SnO₂ doped films as shown in Fig 2(a), the phases of SnO₂, BaSnO₃, $Y_2Cu_2O_5$, and CuO were detected. Among them, large increments of peak intensities for BaSnO₃, $Y_2Cu_2O_5$ and CuO

peak were confirmed as the concentration increase of $SnO₂$, but no increment was detected in $SnO₂$ peak. From these results, it is considered that the most of $SnO₂$ particles were combined with Ba and then changed to BaSnO₃ during heat treatment. While, the phases of ZrO_2 , $BaZrO_3$, $Y_2Cu_2O_5$, and CuO were detected in the YBCO film ZrO_2 doped as shown in Fig 2(b). Among them, large increment for $ZrO₂$ peak and small increment for $Y₂Cu₂O₅$ and CuO peaks were observed with the increase of $ZrO₂$ addition, but the peak of BaZrO₃ was hardly increased. Thus, it is suggested that many $ZrO₂$ particles in precursors exist as same composition even after heating.

3.2. Surface morphology

To discuss the surface morphology of YBCO films with nano-particles doped, we observed the surface of YBCO films by SEM. Fig 3 shows the SEM images of surface for YBCO films. In the pure YBCO film as shown in Fig 3(a), *c*-axis oriented YBCO crystals were observed. In $SnO₂$ doped film as shown in Fig 3(b), segregation of particles with the diameter of about $1 \mu m$ was observed on the surface. On the other hand, segregation of particles was detected slightly on the surface for YBCO film with $ZrO₂$ addition as shown in Fig 3(c).

Fig. 3. SEM images of film surface for (a) pure YBCO, (b) YBCO with SnO₂ addition, and (c) YBCO with ZrO₂ addition.

Fig. 4. SEM-EDX mapping images of YBCO films with (a) $SnO₂ 2 mol%$ addition and (b) $ZrO₂ 2 mol%$ addition.

In order to clarify the compositional element for these segregated precipitates as seen in Fig 3(b) and (c), SEM-EDX measurement for element mapping was performed. As shown in Fig 4(a) and (b), Cu oxide is observed where particles existed on the surface of both $SnO₂$ doped film and $ZrO₂$ doped one. Especially, much Cu oxide particles were observed for YBCO film with $SnO₂$ addition. From the results both XRD measurement and surface morphology observation, it can be considered that many CuO particles were remained for YBCO film with SnO₂ addition because of the result of reaction between $SnO₂$ and Ba during heat treatment. On the other hand, less CuO particles were observed for YBCO film with $ZrO₂$ addition, suggesting less $ZrO₂$ react with Ba during heating.

3.3. Superconducting properties

Fig 5 shows T_c values of pure YBCO films and YBCO films with 2 mol% nano-particles. T_c of YBCO films with SnO₂ and ZrO₂ addition were 90.7 K and 91.5 K, respectively, in comparison to pure YBCO film, 91.8 K. It is indicated that no degradation of T_C was recognized in YBCO films by introducing nano-particles.

Fig 6 shows dependences of J_C on magnetic field for pure YBCO film and YBCO films with 2 mol% nano-particles addition in magnetic field applied parallel to *c*-axis (B //*c*) at 77 K. *J*_C in self field (J_c ^{s.f.}) of SnO₂ doped film and ZrO₂ doped one were 2.9 MA/cm² and 3.6 MA/cm², respectively, in comparison to pure YBCO film, 4.5 MA/cm². *J*_C in 3 T of SnO_2 doped was 0.14 MA/cm², and that of ZrO_2 doped film was 0.07 MA/cm². *J*_C of both YBCO films with nanoparticles added was enhanced in comparison to pure YBCO in low magnetic field. And J_C of SnO₂ doped film was higher than pure YBCO in all magnetic fields. As a result, it is suggested that nano-particles doped in YBCO films acted as pinning centers.

Fig. 5. *T*C behavior of YBCO films with 2 mol% nano-particles addition. Fig. 6. *J*C in magnetic fields at 77 K in **B**//*c*-axis.

3.4. Growth process of YBCO with nano-particles

According to the previous research [7-8], it was predicted that $SnO₂$ in precursors dissolved temporality during heat treatment and then combined with Ba to be BaSnO₃. By based on this predict, it was expected that similar tendency was also seen strongly in the case of smaller particles as the reaction from ZrO_2 to BaZrO₃. However, as seen in results of Fig 3 and Fig 4, the formation of BaZrO₃ was hardly confirmed in case of ZrO₂ addition. Therefore, it is considered that BaSnO₃ particles were formed not by the process of decomposing $SnO₂$ but by peritectic reaction between $SnO₂$ and Ba during heating.

On the other hand, ZrO₂ nano-particles could be expected for introducing smaller APCs in YBCO film. It is under investigating the effect of higher concentration addition of nano-particles into YBCO films and the optimization of crystallization conditions. Also, it is important to observe microstructures for identification of APCs in YBCO films in detail.

4. Conclusion

YBCO films were grown by a MOD process using TFA initial solutions containing nano-particles such as $SnO₂$ and $ZrO₂$ as pinning centers to investigate the growth process of YBCO film with nano-particles. It is considered that most of SnO₂ particles in precursors react with Ba and form BaSnO₃ during heat treatment. J_C in magnetic fields of SnO₂ doped film was enhanced in comparison to pure YBCO film. In order to obtain higher J_C in magnetic fields, it is necessary to control doping concentration of nano-particles into YBCO films and to optimize crystallization condition.

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